

X-ray amplification with laser plasma and its applicability to EUV-FEL

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Plan

- Introduction
- SPring-8 Compact SASE Sources
- Inner-shell Laser with Two-Color SASE pulses
- XFEL Amplification with Laser Plasma
- Energy Recovery Bilinear Accelerator
- Concluding Remarks

Introduction



- Development of laser-based EUV sources for semiconductor lithography is ongoing.
- In addition, accelerator-based EUV sources are attracting attention regardless of their high cost.
- Appropriate combinations between laser and accelerator could reduce both size and cost of the light sources.
- Here we introduce the recent status of SACLA and recent results of XFEL amplification with laser plasma.
- If the above scheme could be used for EUV source, a complete new way of light source development may be envisaged.

Interdependence between Accelerator and Light Communities





IPAC2015, Richmond

Compact SASE Source

- Short-period, in-vacuum undulators can reduce the electron energy to generate XFEL light with a certain photon energy.
- SPring-8 Angstrom Compact Laser (SACLA) is the world's first XFEL based on this 'compact' concept.



Thermionic e-gun to generate highquality electron beam

High-gradient C-band accelerator





SACLA Prototype Construction

250 MeV Prototype, Total Length: 60 m, Target Wavelength: 60 nm



First Lasing at 49 nm (June 20, 2006)



Electron Beam Profile





E = 250 MeVCharge/Pulse $\leq 0.25 \text{ nC}$ Emittance $\leq 2\pi \text{mm} \cdot \text{mrad}$ Pulse Length $\leq 2 \text{ ps}$ Wavelength = 49 nm

Max. Power = 110 kW

SACLA

(SPring-8 Angstrom Compact free electron LAser)

X-Ray Free Electron Laser with 8 GeV electron Liniac 700 m length including experimental building Completed in March 2011 Open for public users (domestic and international)

> Beam Transport to Storage Ring

Photon Beam Colliding Facility In-vacuum Undulator

The first XFEL that collocate with a 3rd generation SR source. The first "compact" XFEL to have a length of 700 meters.

Thermionic

Cathode

C-band

Acc.

General Information about SACLA

- 5,861 h operation with 4,026 h user time with 130 h down time (~3.2% of user time) in 2016 FY
- MTBF: 67 min for **BL2/3**(2016 FY)
- **3** beam lines are in operation. **2** pending construction.
- **1188** visiting users in 2016 FY
- 151 proposals submitted, 77 approved (51 %) in 2016 FY
- User affiliation: 23.4% from abroad, 26.0% from national/public institutes, 42.8% from universities, 7.8% from industries
- Operation Budget: **5.79** BJPY in 2016 FY
- 274 publications (2012~) in refereed journals



Laser Broke 1.0 Angstrom Barrier





Laser Wavelength (Angstrom)

3 FEL(2X+1SX) Beamlines Available



Help Promote Sustainable Development



- PSII molecular structure was determined by using SPring-8 and SACLA
- Reaction dynamics is under investigation with SACLA
- The structure of reaction center help develop the artificial photosynthesis catalysts

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Native structure of photosystem II at 1.95 Å resolution viewed by femtosecond X-ray pulses

JELERK

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New beamline: BL2

Deficiency of beamtime severely limits research activities with XFEL

Construction of 2nd hard X-ray FEL beamline for increasing capacity



Undulators installed in summer 2014

accelerator hall (~ 400 m)



First lasing on Oct 20th, 2014





undulator hall (~ 200 m)



- Evacuate SCSS from the original tunnel, and relocate to SACLA undulator hall and connect to BL1
- E-beam driver for EUV/SX FEL generation, independent of the SACLA main linac
- Completed in 2015 summer with 450 MeV (λ ~30 nm with λ_{U} =18 mm)

Commissioning: First SASE lasing on Oct 7, 2015

Pulse energy : 10~20 uJ

ID#1: K=2.1 ID#2: tuning K



Two-color operation with variable-gap undulators



Hara et al, Nature Commun 2014

Achievement of Hard X-ray Cu-Ka atomic laser (ASE) 9 keV Two-stage





Achievement of Hard X-ray Cu-Ka atomic laser

Challenge for increasing XFEL pulse energy





Results: Spectra of amplified pulses



Inubushi et al., submitted



Hit rate of amplification: ~15% \Rightarrow ^{3/20/2016 T. Ishikawa, OSA Compact Light Sources meeting, Hilton Long Beach, California, USA Photon energy (keV) 21 Timing Jitter and fluctuation of XFEL}

Multi-stage amplification: X-ray laser beyond TW level

Inubushi et al., submitted



Bilinear Accelerator for ERL-EUV-FEL



~ 50 m

Photon Wavelength	13.5 nm
Linac Energy	280 MeV
Repetition	10 MHz ~ 100 MHz
Pulse Energy	$0.1 \ \mu J$ (5 th harmonics)
Undulator Period	20 mm
Undulator K-value	1.5
Amplification	x 100 ~ x 1000

ERL-Ring design (e.g. KEK) ~ 4,000 m² area is needed for 1 EUV line. This design ~ 500 m² area is needed for 2 EUV lines. **x16 space efficiency**

Concluding Remarks

- Atomic laser achieved by using SACLA's two color operation, and laser-plasma amplification of XFEL pulse were introduced.
- Possible application of laser-plasma amplification is 13.5 nm high-power EUV source. A bilinear accelerator FEL for this purpose has been proposed.
- In the SPring-8 site, there are some light sources which can emit moderate intensity 13.5 nm light (New-SUBARU SR and SCSS+ EUV-FEL).

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3/20/2016 T. Ishikawa, OSA Compact Children Specces vice mg. Hill of the Bya Chall firmi Challer in Challer in